

PIN DESCRIPTION and PAD DIMENSIONS

| Name | ١⁄٥ | Description | | Pad dimensions [µm] | |
|------|-----|--|--|---------------------|-----|
| Name | | | | x | Y |
| INHN | ĩ | Output state control input. High impedance when LOW (oscillator stops). Power-saving pull-up resistor built-in. | | 151 | 277 |
| XT | 1 | Amplifier input | Crystal connection pins. | 238 | 131 |
| XTN | 0 | Amplifier output | Crystal is connected between XT and XTN. | 512 | 131 |
| VSS | 10 | Ground | | 588 | 345 |
| Q | 0 | Output. Output frequency (to, fo/2, to/4, to/8, fo/16) determined by internal connection | | 588 | 548 |
| VDD | - | Supply voltage | | 131 | 548 |



Instructions:

- A. Standard process flow for die-attach and wire bond of semiconductor die in ceramic SMD is acceptable.
- B. Final assemblies are nitrogen purged and vacuum packed for transportation. Trays used for shipping ceramic carriers are acceptable.
- C. Label shall at minimum include part number, quantity, and Lot Code.
- D. Part number shall take the form ASM5070-5014ALx where x = version number 1 through 5.

ASM5070-CF5014AL1 ASM5070-CF5014AL2 ASM5070-CF5014AL3 ASM5070-CF5014AL4 ASM5070-CF5014AL5

| Item ID | Description | Qty / Unit |
|-------------|------------------------------|------------|
| S5070CLK8 | 4-pad 5mm x 7mm ceramic base | 1 |
| 5014ALx-2 * | IC Oscillator 220µm thick | 1 |
| | | |

This ceramic base package has different interior layout than Rev A, however the package size and height and Kovar ring are specified the same as Rev A.

Final pad orientation remain the same.

Pad 1 = Enable/Disable Pad 2 = VSS or Ground Pad 3 = Q or output Pad 4 = VDD

| Revision | Date | Reason |
|----------|------------|--|
| В | 2017-04-22 | Package Base change (Same form-fit-function) |
| А | 2009/10/14 | Update Instruction C Time/Temp to include approved alternate |
| - | 2009/8/10 | Original Issue (Type II B) |

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